

## PNP SILICON EPITAXIAL PLANAR TRANSISTORS



#### For General Purpose and Switching Applications

These transistors are subdivided into three groups -16 , -25 , -40 according to their current gain.

### ABSOLUTE MAXIMUM RATINGS (T<sub>a</sub>=25°C unless specified otherwise)

DESCRIPTION	SYMBOL	VALUE	UNITS
Collector Base Voltage			
BC807W	$V_{_{CBO}}$	50	V
BC808W		30	
Collector Emitter Voltage			
BC807W	$V_{ceo}$	45	V
BC808W		25	
Emitter Base Voltage	$V_{EBO}$	5	V
Collector Current	I <sub>c</sub>	500	mA
Peak Collector Current	I <sub>CM</sub>	1	А
Peak Base Current	I <sub>BM</sub>	200	mA
Power Dissipation	P <sub>tot</sub>	200	mW
Thermal Resistance , Junction to Ambient	R <sub>eJA</sub>	625 <sup>1)</sup>	K/W
Junction Temperature	T <sub>j</sub>	150	°C
Storage Temperature Range	Τ <sub>s</sub>	-65 to +150	°C

1) Transistor mounted on an FR4 printed -circuit board.

BC807W\_808W Rev 290910D

BC807W / BC808W

SOT-323 Plastic Package

# PNP SILICON EPITAXIAL PLANAR TRANSISTORS



BC807W / BC808W

SOT-323 Plastic Package

Characterstics	at T <sub>amb</sub>	= 25	°C
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DESCRIPTION	SYMBOL	TEST CONDITION	MIN	МАХ	UNITS
DC Current Gain					
-16W	h <sub>FE</sub>		100	250	-
-25W	h <sub>FE</sub>	V <sub>ce</sub> =1V, I <sub>c</sub> =100 mA	160	400	-
-40W	h <sub>FE</sub>		250	600	-
	h <sub>FE</sub>	V <sub>CE</sub> =1V , I <sub>C</sub> = 500mA	40	-	-
Collector Base Breakdown Voltage					
BC807W	V V <sub>(BR)CBO</sub>	Ι <sub>C</sub> = 10μΑ	50	-	V
BC808W	1		30		
Collector Emitter Breakdown Voltage					
BC807W	V V <sub>(BR)CEO</sub>	I <sub>c</sub> =1mA	45	-	V
BC808W			25		
Emitter Base Breakdown Voltage	V <sub>(BR)EBO</sub>	I <sub>E</sub> =10 uA	5	-	V
Collector Emitter Saturation Voltage	V <sub>CEsat</sub>	$I_{c}$ =500 mA , $I_{B}$ = 50 mA	-	0.7	V
Base Emitter Voltage	V <sub>BE(ON)</sub>	$I_{\rm C}$ =500 mA , $V_{\rm CE}$ =1V	-	1.2	V
Collector Cutoff Current	I <sub>CBO</sub>	V <sub>CB</sub> =20V	-	100	nA
		V <sub>CB</sub> =20V , Tj=150°C	-	5.0	μΑ
Emitter Cutoff Current	I <sub>EBO</sub>	V <sub>EB</sub> =5V	-	100	nA
Transition Frequency	f	$V_{CE}$ =5V , $I_{C}$ =10mA ,	80	-	MHz
	Т	f=100MHz	00		
Collector Capacitance	C <sub>c</sub>	V <sub>CB</sub> =10V , f=1MHz	-	10	pF

BC807W\_808W Rev 290910D

SOT-323 **Plastic Package** 



PACKAGE SOT-323

DIM	MIN	MAX
A	1.25	1.35
В	2.02	2.18
С	1.20	1.30
D	1.25	1.35
E	2.10	2.20
F	0.27	0.33
G	0.95	1.00
Н	0.35	4.00
J	0.09	0.15
K	0.25	0.33
L	0.00	0.10
М	R 0.15	R 0.20

DIMENSIONS ARE IN mm

PIN CONFIGURATION

- 1. BASE
- 2. EMITTER
- 3. COLLECTOR

PACKING :- 3K/REEL

SOT-323 Plastic Package

**Component Disposal Instructions** 

- 1. CDIL Semiconductor Devices are RoHS compliant, customers are requested to please dispose as per prevailing Environmental Legislation of their Country.
- 2. In Europe, please dispose as per EU Directive 2002/96/EC on Waste Electrical and Electronic Equipment (WEEE).

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